TOSHIBA Transistor Silicon NPN Epitaxial Type

# 2SC5712

High-Speed Switching Applications
DC-DC Converter Applications
DC-AC Converter Applications

- High DC current gain:  $h_{FE} = 400$  to 1000 ( $I_{C} = 0.3$  A)
- Low collector-emitter saturation voltage: VCE (sat) = 0.14 V (max)
- High-speed switching:  $t_f = 120$  ns (typ.)

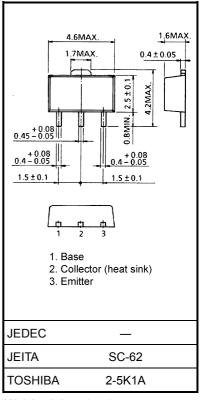
### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	100	V	
Collector-emitter voltage		V <sub>CEX</sub>	80	V	
		V <sub>CEO</sub>	50		
Emitter-base voltage		V <sub>EBO</sub>	7	V	
Collector current	DC	IC	3.0	Α	
	Pulse	I <sub>CP</sub>	5.0		
Base current		ΙΒ	300	mA	
Collector power dissipation	DC	PC	1.0	W	
	t = 10 s	(Note)	2.5		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	

Note: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

#### **Industrial Applications**

Unit: mm



Weight: 0.05 g (typ.)

## **Electrical Characteristics (Ta = 25°C)**

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	V <sub>CB</sub> = 100 V, I <sub>E</sub> = 0	_	_	100	nA
Emitter cut-off current		I <sub>EBO</sub>	V <sub>EB</sub> = 7 V, I <sub>C</sub> = 0	_	_	100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	50	_	_	V
DC current gain		h <sub>FE</sub> (1)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 0.3 A	400	_	1000	
		h <sub>FE</sub> (2)	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1 A	200	_	_	
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 20 mA	_	_	0.14	V
Base-emitter saturation voltage		V <sub>BE</sub> (sat)	I <sub>C</sub> = 1 A, I <sub>B</sub> = 20 mA	_	_	1.10	V
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	13	_	pF
Switching time	Rise time	t <sub>r</sub>	See Figure 1 circuit diagram.	_	40	_	
	Storage time	t <sub>stg</sub>	$V_{CC} \simeq 30 \text{ V}, \text{ R}_{L} = 30 \Omega$	_	500	_	ns
	Fall time	t <sub>f</sub>	$I_{B1} = -I_{B2} = 33.3 \text{ mA}$	_	120	_	

# Marking

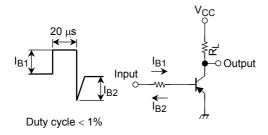
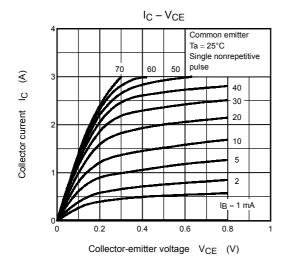
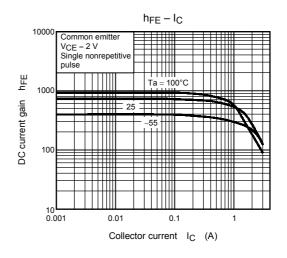
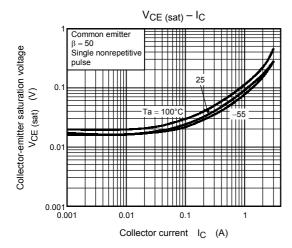


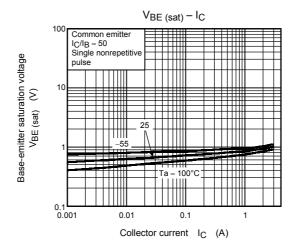


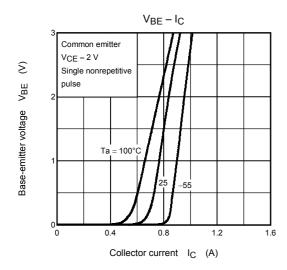
Figure 1 Switching Time Test Circuit & Timing Chart

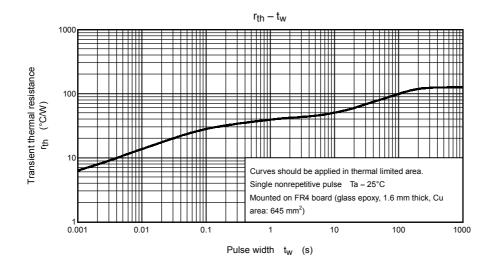


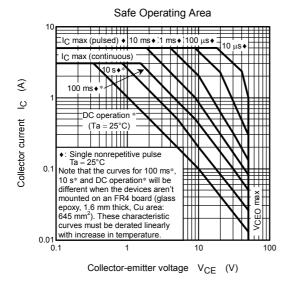












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